



Ultra-Small, Overvoltage Protection/ Detection Circuits

General Description

The MAX16010–MAX16014 is a family of ultra-small, low-power, overvoltage protection circuits for high-voltage, high-transient systems such as those found in automotive, telecom, and industrial applications. These devices operate over a wide 5.5V to 72V supply voltage range, making them also suitable for other applications such as battery stacks, notebook computers, and servers.

The MAX16010 and MAX16011 offer two independent comparators for monitoring both undervoltage and overvoltage conditions. These comparators offer open-drain outputs capable of handling voltages up to 72V. The MAX16010 features complementary enable inputs (EN/EN), while the MAX16011 features an active-high enable input and a selectable active-high/low OUTB output.

The MAX16012 offers a single comparator and an independent reference output. The reference output can be directly connected to either the inverting or noninverting input to select the comparator output logic.

The MAX16013 and MAX16014 are overvoltage protection circuits that are capable of driving two p-channel MOSFETs to prevent reverse-battery and overvoltage conditions. One MOSFET (P1) eliminates the need for external diodes, thus minimizing the input voltage drop. The second MOSFET (P2) isolates the load or regulates the output voltage during an overvoltage condition. The MAX16014 keeps the MOSFET (P2) latched off until the input power is cycled.

The MAX16010 and MAX16011 are available in small 8-pin TDFN packages, while the MAX16012/MAX16013/MAX16014 are available in small 6-pin TDFN packages. These devices are fully specified from -40°C to +125°C.

Applications

Automotive
Industrial
48V Telecom/Server/Networking
FireWire®
Notebook Computers
Multicell Battery-Stack Powered Equipment

FireWire is a registered trademark of Apple, Inc.

Pin Configurations appear at end of data sheet.

Features

- ◆ Wide 5.5V to 72V Supply Voltage Range
- ◆ Open-Drain Outputs Up to 72V
(MAX16010/MAX16011/MAX16012)
- ◆ Fast 2 μ s (max) Propagation Delay
- ◆ Internal Undervoltage Lockout
- ◆ p-Channel MOSFET Latches Off After an
Overvoltage Condition (MAX16014)
- ◆ Adjustable Overvoltage Threshold
- ◆ -40°C to +125°C Operating Temperature Range
- ◆ Small 3mm x 3mm TDFN Package

Ordering Information

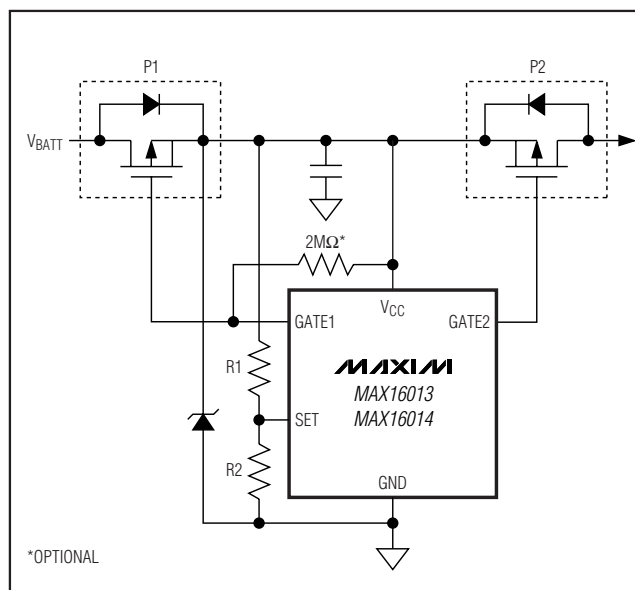
PART*	TEMP RANGE	PIN-PACKAGE
MAX16010TA_-T	-40°C to +125°C	8 TDFN-EP**
MAX16011TA_-T	-40°C to +125°C	8 TDFN-EP**
MAX16012TT-T	-40°C to +125°C	6 TDFN-EP**
MAX16013TT-T	-40°C to +125°C	6 TDFN-EP**
MAX16014TT-T	-40°C to +125°C	6 TDFN-EP**

Note: Replace the “_” with “A” for 0.5% hysteresis, “B” for 5% hysteresis, and “C” for 7.5% hysteresis.

*Replace -T with +T for lead-free packages.

**EP = Exposed pad.

Typical Operating Circuit



*OPTIONAL

MAXIM**Maxim Integrated Products 1**

For pricing, delivery, and ordering information, please contact Maxim Direct at 1-888-629-4642, or visit Maxim's website at www.maxim-ic.com.

MAX16010-MAX16014

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ABSOLUTE MAXIMUM RATINGS

(All pins referenced to GND, unless otherwise noted.)

V _{CC}	-0.3V to +80V
EN, $\overline{\text{EN}}$, LOGIC.....	-0.3V to (V _{CC} + 0.3V)
INA+, INB-, IN+, IN-, REF, SET	-0.3V to +12V
OUTA, OUTB, OUT.....	-0.3V to +80V
GATE1, GATE2 to V _{CC}	-12V to +0.3V
GATE1, GATE2.....	-0.3V to (V _{CC} + 0.3V)
Current Sink/Source (all pins).....	50mA

Continuous Power Dissipation (T_A = +70°C)

6-Pin TDFN (derate 18.2mW/°C above +70°C)1455mW

8-Pin TDFN (derate 18.2mW/°C above +70°C)1455mW

Operating Temperature Range-40°C to +125°C

Maximum Junction Temperature+150°C

Storage Temperature Range-60°C to +150°C

Lead Temperature (soldering, 10s).....+300°C

Stresses beyond those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

(V_{CC} = 14V, T_A = -40°C to +125°C, unless otherwise noted. Typical values are at T_A = +25°C.) (Note 1)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
Supply Voltage Range	V _{CC}			5.5		72.0	V
Input Supply Current	I _{CC}	No load	V _{CC} = 12V	20	30	μA	
			V _{CC} = 48V	25	40		
V _{CC} Undervoltage Lockout	V _{UVLO}	V _{CC} rising, part enabled, V _{INA+} = 2V, OUTA deasserted (MAX16010/MAX16011), V _{IN} = 2V, V _{OUT} deasserted (MAX16012), V _{SET} = 0V, GATE2 = V _{CLMP} (MAX16013/MAX16014)		4.75	5	5.25	V
INA+/INB-/SET Threshold Voltage	V _{TH+}			1.215	1.245	1.265	V
	V _{TH-}	0.5% hysteresis, MAX16010/MAX16011		1.21	1.223	1.26	
		5.0% hysteresis, MAX16010/MAX16011/MAX16013/MAX16014		1.15	1.18	1.21	
		7.5% hysteresis MAX16010/MAX16011		1.12	1.15	1.18	
Threshold-Voltage Hysteresis		MAX16010TAA/MAX16011TAA		0.5		%	
		MAX16010TAB/MAX16011TAB/MAX16013/MAX16014		5.0			
		MAX16010TAC/MAX16011TAC		7.5			
SET/IN_ Input Current		SET/IN_ = 2V		-100		+100	nA
IN_ Operating Voltage Range				0		4	V
Startup Response Time	t _{START}	V _{CC} rising from 0 to 5.5V		100			μs
IN_ to OUT/SET to GATE2 Propagation Delay	t _{PROP}	IN_/SET rising from (V _{TH} - 100mV) to (V _{TH} + 100mV) or falling from (V _{TH} + 100mV) to (V _{TH} - 100mV) (no load)				2	μs
OUT_ Output-Voltage Low	V _{OL}	V _{CC} ≥ 5.5V, I _{SINK} = 3.2mA				0.4	V
		V _{CC} ≥ 2.8V, I _{SINK} = 100μA				0.4	V
OUT_ Leakage Current	I _{LEAK}	OUT_ = 72V				500	nA

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MAX16010-MAX16014

ELECTRICAL CHARACTERISTICS (continued)

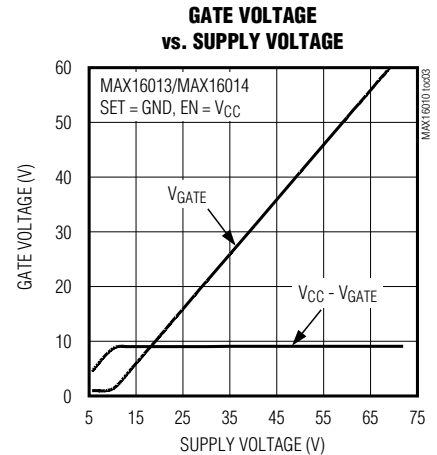
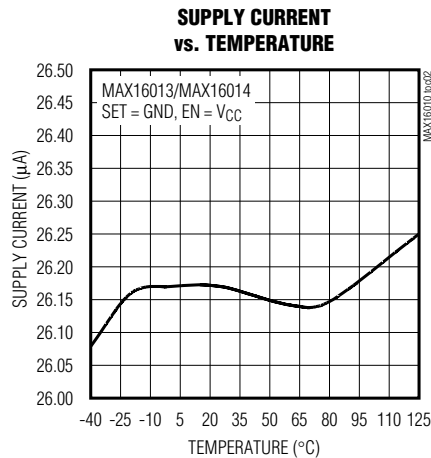
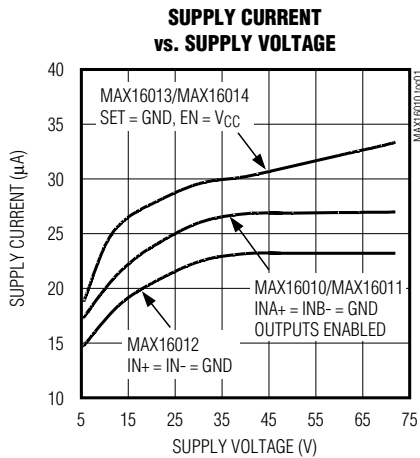
($V_{CC} = 14V$, $T_A = -40^{\circ}C$ to $+125^{\circ}C$, unless otherwise noted. Typical values are at $T_A = +25^{\circ}C$.) (Note 1)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
EN/ $\overline{EN}$, LOGIC Input Voltage	V_{IL}				0.4	V
	V_{IH}		1.4			
EN/ $\overline{EN}$, LOGIC Input Current				1	2	μA
EN/ $\overline{EN}$, LOGIC Pulse Width			10			μs
V_{CC} to GATE_ Output Low Voltage		$I_{GATE_SINK} = 75\mu A$, $I_{GATE_SOURCE} = 1\mu A$, $V_{CC} = 14V$	7		11	V
V_{CC} to GATE_ Clamp Voltage		$V_{CC} = 24V$	12		18	V
MAX16012						
Reference Output Voltage	V_{REF}	No load	1.275	1.3	1.320	V
Reference Short-Circuit Current	I_{SHORT}	REF = GND		100		μA
Reference Load Regulation		Sourcing, $0 \leq I_{REF} \leq 1\mu A$		0.1		mV/ μA
		Sinking, $-1\mu A \leq I_{REF} \leq 0$		0.1		
Input Offset Voltage		$V_{CM} = 0$ to $2V$	-12.5		+12.5	mV
Input Offset Current				3		nA
Input Hysteresis				8		mV
Common-Mode Voltage Range	CMVR		0		2.0	V
Common-Mode Rejection Ratio	CMRR	DC		70		dB
Comparator Power-Supply Rejection Ratio	PSRR	MAX16012, DC		70		dB

Note 1: 100% production tested at $T_A = +25^{\circ}C$ and $T_A = +125^{\circ}C$. Specifications at $T_A = -40^{\circ}C$ are guaranteed by design.

Typical Operating Characteristics

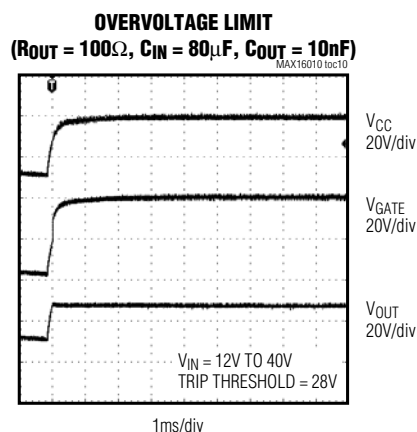
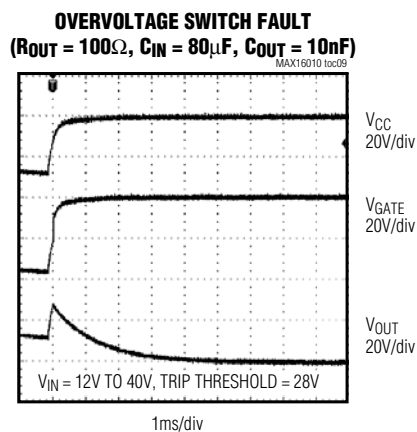
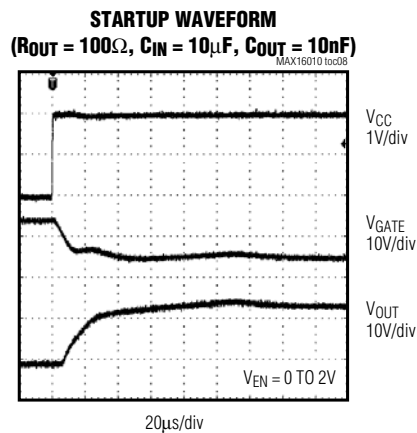
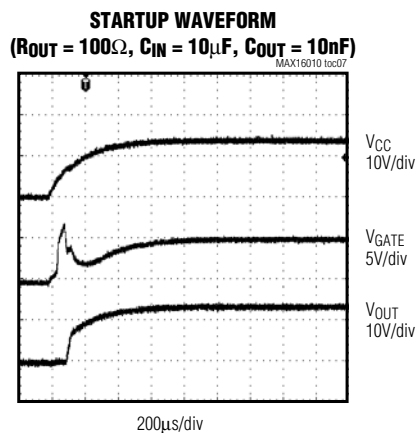
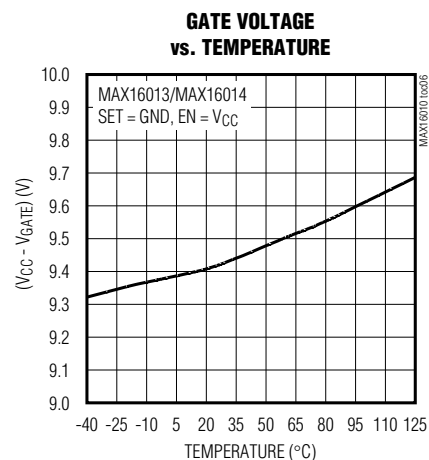
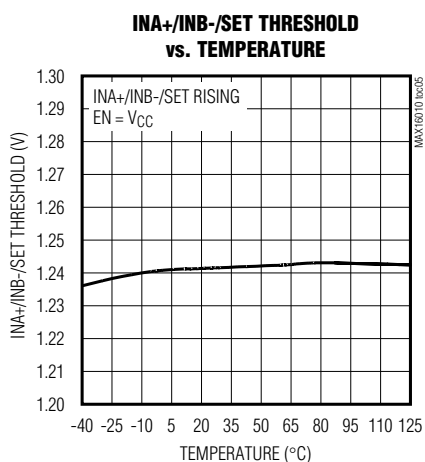
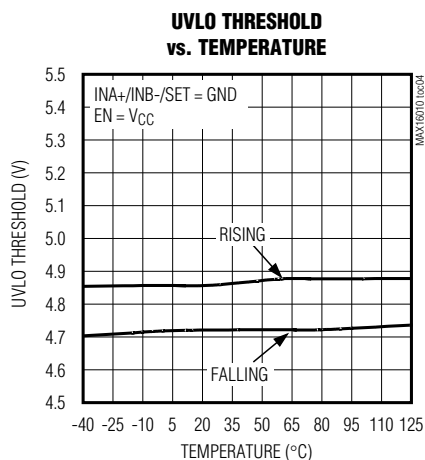
($V_{IN} = 14V$, $T_A = +25^{\circ}C$, unless otherwise noted.)



Ultra-Small, Overvoltage Protection/ Detection Circuits

Typical Operating Characteristics (continued)

($V_{IN} = 14V$, $T_A = +25^\circ C$, unless otherwise noted.)



Ultra-Small, Overvoltage Protection/ Detection Circuits

Pin Description

MAX16010-MAX16014

PIN				NAME	FUNCTION
MAX16010	MAX16011	MAX16012	MAX16013 MAX16014		
1	1	1	1	V _{CC}	Positive-Supply Input Voltage. Connect V _{CC} to a 5.5V to 72V supply.
2	2	2	2	GND	Ground
3	—	—	—	$\overline{\text{EN}}$	Active-Low Enable Input. Drive $\overline{\text{EN}}$ low to turn on the voltage detectors. Drive $\overline{\text{EN}}$ high to force the OUTA and OUTB outputs low. EN is internally pulled up to V _{CC} . Connect $\overline{\text{EN}}$ to GND if not used.
4	4	—	—	OUTB	Open-Drain Monitor B Output. Connect a pullup resistor from OUTB to V _{CC} . OUTB goes low when INB- exceeds V _{TH+} and goes high when INB- drops below V _{TH-} (with LOGIC connected to GND for the MAX16011). Drive LOGIC high to reverse OUTB's logic state. OUTB is usually used as an overvoltage output. OUTB goes low (LOGIC = low) or high (LOGIC = high) when V _{CC} drops below the UVLO threshold voltage.
5	5	—	—	INB-	Adjustable Voltage Monitor Threshold Input
6	6	—	5	EN	Active-High ENABLE Input. For the MAX16010/MAX16011, drive EN high to turn on the voltage detectors. Drive EN low to force OUTA low and OUTB low (LOGIC = low) or high (LOGIC = high). For the MAX16013/MAX16014, drive EN high to enhance the p-channel MOSFET (P2), and drive EN low to turn off the MOSFET. EN is internally pulled down to GND. Connect EN to V _{CC} if not used.
7	7	—	—	OUTA	Open-Drain Monitor A Output. Connect a pullup resistor from OUTA to V _{CC} . OUTA goes low when INA+ drops below V _{TH-} and goes high when INA+ exceeds V _{TH+} . OUTA is usually used as an undervoltage output. OUTA also goes low when V _{CC} drops below the UVLO threshold voltage.
8	8	—	—	INA+	Adjustable Voltage Monitor Threshold Input
—	3	—	—	LOGIC	OUTB Logic-Select Input. Connect LOGIC to GND or V _{CC} to configure the OUTB logic. See the MAX16011 output logic table.
—	—	3	—	OUT	Open-Drain Comparator Output. Connect a pullup resistor from OUT to V _{CC} . OUT goes low when IN+ drops below IN-. OUT goes high when IN+ exceeds IN-.
—	—	4	—	IN-	Inverting Comparator Input
—	—	5	—	REF	Internal 1.30V Reference Output. Connect REF to IN+ for active-low output. Connect REF to IN- for active-high output. REF can source and sink up to 1μA. Leave REF floating if not used. REF output is stable with capacitive loads from 0 to 50pF.
—	—	6	—	IN+	Noninverting Comparator Input
—	—	—	3	GATE2	Gate-Driver Output. Connect GATE2 to the gate of an external p-channel MOSFET pass switch. GATE2 is driven low to the higher of V _{CC} - 10V or GND during normal operations and quickly shorted to V _{CC} during an overvoltage condition (SET above the internal threshold). GATE2 is shorted to V _{CC} when the supply voltage goes below the UVLO threshold voltage. GATE2 is shorted to V _{CC} when EN is low.
—	—	—	4	SET	Device Overvoltage Threshold Adjustment Input. Connect SET to an external resistive divider network to adjust the desired overvoltage disable or overvoltage limit threshold (see the <i>Typical Application Circuit</i> and <i>Overvoltage Limiter</i> section).
—	—	—	6	GATE1	Gate-Driver Output. Connect GATE1 to the gate of an external p-channel MOSFET to provide low drop reverse voltage protection.
—	—	—	—	EP	Exposed Pad. Connect EP to GND.

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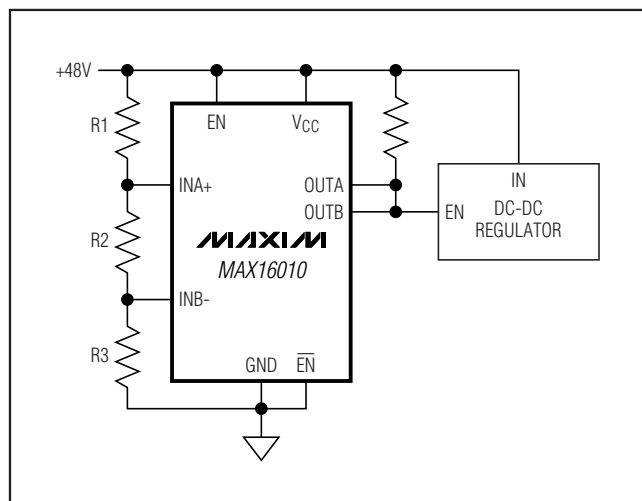


Figure 1. MAX16010 Monitor Circuit

Detailed Description

The MAX16010-MAX16014 is a family of ultra-small, low-power, overvoltage protection circuits for high-voltage, high-transient systems such as those found in automotive, telecom, and industrial applications. These devices operate over a wide 5.5V to 72V supply voltage range, making them also suitable for other applications such as battery stacks, notebook computers, and servers.

The MAX16010 and MAX16011 offer two independent comparators for monitoring both undervoltage and overvoltage conditions. These comparators offer open-drain outputs capable of handling voltages up to 72V. The MAX16010 features complementary enable inputs (EN/EN), while the MAX16011 features an active-high enable input and a selectable active-high/low OUTB output.

The MAX16012 offers a single comparator and an independent reference output. The reference output can be directly connected to either the inverting or noninverting input to select the comparator output logic.

The MAX16013 and MAX16014 are overvoltage protection circuits that are capable of driving two p-channel MOSFETs to prevent reverse battery and overvoltage conditions. One MOSFET (P1) eliminates the need for external diodes, thus minimizing the input voltage drop. While the second MOSFET (P2) isolates the load or regulates the output voltage during an overvoltage condition. The MAX16014 keeps the MOSFET (P2) latched off until the input power is cycled.

Voltage Monitoring

The MAX16010/MAX16011 include undervoltage and overvoltage comparators for window detection (see Figure 1). OUT₋ asserts high when the monitored voltage is within the selected "window." OUTA asserts low when the monitored voltage falls below the lower (V_{TRIPLOW}) limit of the window, or OUTB asserts low if the monitored voltage exceeds the upper limit (V_{TRIPHIGH}). The application in Figure 1 shows OUT₋ enabling the DC-DC converter when the monitored voltage is in the selected window.

The resistor values R1, R2, and R3 can be calculated as follows:

$$V_{TRIPLOW} = V_{TH-} \left(\frac{R_{TOTAL}}{R2 + R3} \right)$$

$$V_{TRIPHIGH} = V_{TH+} \left(\frac{R_{TOTAL}}{R3} \right)$$

where $R_{TOTAL} = R1 + R2 + R3$.

Use the following steps to determine the values for R1, R2, and R3.

- 1) Choose a value for R_{TOTAL} , the sum of R1, R2, and R3. Because the MAX16010/MAX16011 have very high input impedance, R_{TOTAL} can be up to 5MΩ.
- 2) Calculate R3 based on R_{TOTAL} and the desired upper trip point:

$$R3 = \frac{V_{TH+} \times R_{TOTAL}}{V_{TRIPHIGH}}$$

- 3) Calculate R2 based on R_{TOTAL} , R3, and the desired lower trip point:

$$R2 = \frac{V_{TH-} \times R_{TOTAL}}{V_{TRIPLOW}} - R3$$

- 4) Calculate R1 based on R_{TOTAL} , R3, and R2:

$$R1 = R_{TOTAL} - R2 - R3$$

The MAX16012 has both inputs of the comparator available with an integrated 1.30V reference (REF). When the voltage at IN₊ is greater than the voltage at IN₋ then OUT goes high. When the voltage at IN₋ is greater than the voltage at IN₊ then OUT goes low. Connect REF to IN₊ or IN₋ to set the reference voltage value. Use an external resistive divider to set the monitored voltage threshold.

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MAX16010-MAX16014

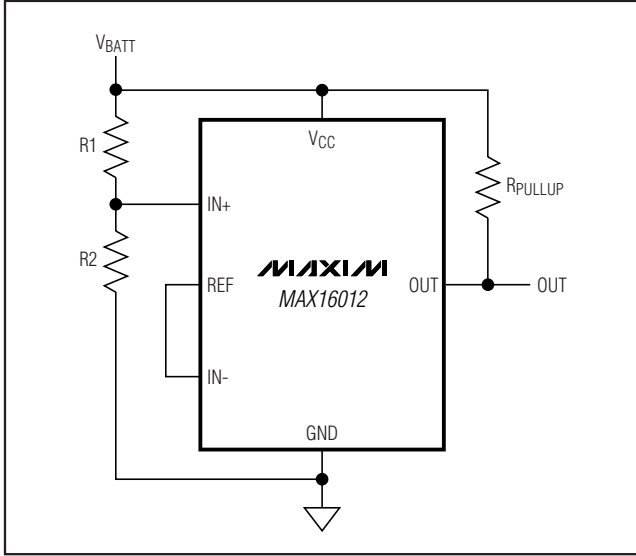


Figure 2. Typical Operating Circuit for the MAX16012

The MAX16013/MAX16014 can be configured as an overvoltage switch controller to turn on/off a load (see the *Typical Application Circuit*). When the programmed overvoltage threshold is tripped, the internal fast comparator turns off the external p-channel MOSFET (P2), pulling GATE2 to VCC to disconnect the power source from the load. When the monitored voltage goes below the adjusted overvoltage threshold, the MAX16013 enhances GATE2, reconnecting the load to the power source (toggle ENABLE on the MAX16014 to reconnect the load). The MAX16013 can be configured as an overvoltage limiter switch by connecting the resistive divider to the load instead of VCC (Figure 3). See the *Overvoltage Limiter* section.

Supply Voltage

Connect a 5.5V to 72V supply to VCC for proper operation. For noisy environments, bypass VCC to GND with a 0.1µF or greater capacitor. When VCC falls below the UVLO voltage the following states are present (Table 1).

Table 1. UVLO State (VCC < VUVLO)

PART	OUTA	OUTB	OUT	GATE2
MAX16010	Low	Low	—	—
MAX16011	Low	Low, LOGIC = low High, LOGIC = high	—	—
MAX16012	—	—	Low	—
MAX16013 MAX16014	—	—	—	High

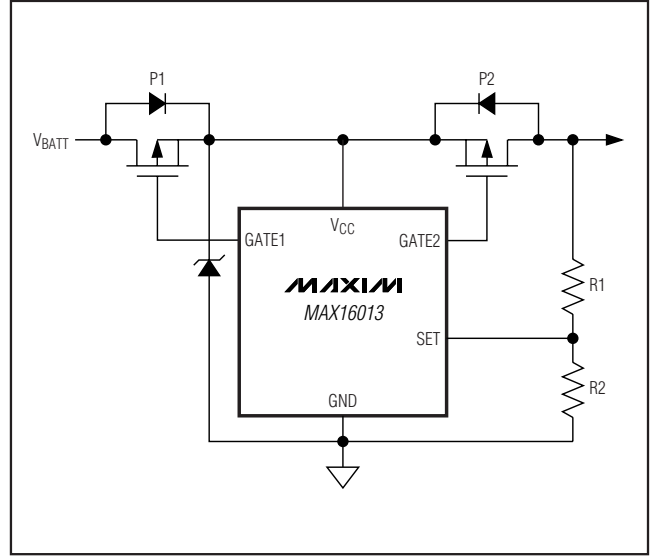


Figure 3. Overvoltage Limiter Protection

Hysteresis

Hysteresis adds noise immunity to the voltage monitors and prevents oscillation due to repeated triggering when the monitored voltage is near the threshold trip voltage. The hysteresis in a comparator creates two trip points: one for the rising input voltage (VTH+) and one for the falling input voltage (VTH-). These thresholds are shown in Figure 4.

Enable Inputs (EN or EN)

The MAX16011 offers an active-high enable input (EN), while the MAX16010 offers both an active-high enable input (EN) and active-low enable input (EN). For the MAX16010, drive EN low or EN high to force the output low. When the device is enabled (EN = high and EN = low) the state of OUTA and OUTB depends on INA+ and INB- logic states.

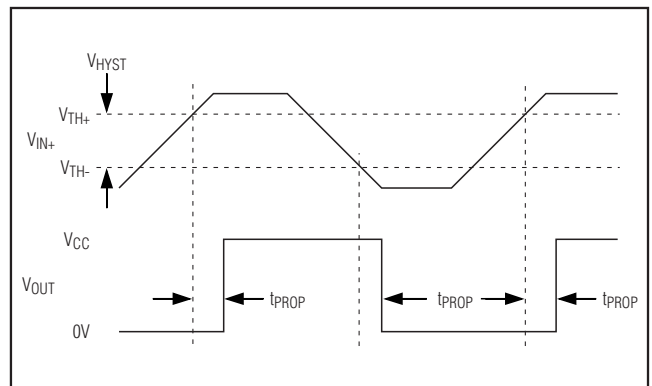


Figure 4. Input and Output Waveforms

Ultra-Small, Overvoltage Protection/ Detection Circuits

Table 2. MAX16011 Output Logic

LOGIC	INA+	INB-	OUTA	OUTB
Low	$> V_{TH+}$	$> V_{TH+}$	High Impedance	Low
Low	$< V_{TH-}$	$< V_{TH-}$	Low	High Impedance
High	$> V_{TH+}$	$> V_{TH+}$	High Impedance	High Impedance
High	$< V_{TH-}$	$< V_{TH-}$	Low	Low

For the MAX16011, drive EN low to force OUTA low, OUTB low when LOGIC = low, and OUTB high when LOGIC = high. When the device is enabled (EN = high) the state of OUTA and OUTB depends on the INA+, INB-, and LOGIC input (see Table 2).

For the MAX16013/MAX16014, drive EN low to pull GATE2 to V_{CC} , turning off the p-channel MOSFET (P2). When the device is enabled (EN = high), GATE2 is pulled to the greater of ($V_{CC} - 10V$) or GND turning on the external MOSFET (P2).

Applications Information

Load Dump

Most automotive applications are powered by a multi-cell, 12V lead-acid battery with a voltage between 9V and 16V (depending on load current, charging status, temperature, battery age, etc.). The battery voltage is distributed throughout the automobile and is locally regulated down to voltages required by the different system modules. Load dump occurs when the alternator is charging the battery and the battery becomes disconnected. Power in the alternator inductance flows into the distributed power system and elevates the voltage seen at each module. The voltage spikes have rise times typically greater than 5ms and decays within several hundred milliseconds but can extend out to 1s or more depending on the characteristics of the charging system. These transients are capable of destroying sensitive electronic equipment on the first fault event.

The MAX16013/MAX16014 provide the ability to disconnect the load from the charging system during an overvoltage condition to protect the module. In addition, the MAX16013 can be configured in a voltage-limiting mode. This allows continuous operation while providing overvoltage protection. See the *Overvoltage Limiter* section.

Input Transients Clamping

When the external MOSFET is turned off during an overvoltage occurrence, stray inductance in the power path may cause voltage ringing to exceed the MAX16013/MAX16014 absolute maximum input (V_{CC}) supply rating. The following techniques are recommended to reduce the effect of transients:

- Minimize stray inductance in the power path using wide traces, and minimize loop area including the power traces and the return ground path.
- Add a zener diode or transient voltage suppressor (TVS) rated below V_{CC} absolute maximum rating (Figure 3).

Overvoltage Limiter

When operating in overvoltage-limiter mode, the MAX16013 drives the external p-channel MOSFET (P2), resulting in the external MOSFET operating as a voltage regulator.

During normal operation, GATE2 is pulled to the greater of ($V_{CC} - 10V$) or GND. The external MOSFET's drain voltage is monitored through a resistor-divider between the P2 output and SET. When the output voltage rises above the adjusted overvoltage threshold, an internal comparator pulls GATE2 to V_{CC} . When the monitored voltage goes below the overvoltage threshold, the p-channel MOSFET (P2) is turned on again. This process continues to keep the voltage at the output regulated to within approximately a 5% window. The output voltage is regulated during the overvoltage transients and the MOSFET (P2) continues to conduct during the overvoltage event, operating in switched-linear mode.

Caution must be exercised when operating the MAX16013 in voltage-limiting mode for long durations due to the MOSFET's power dissipation consideration (see the *MOSFET Selection and Operation* section).

MOSFET Selection and Operation (MAX16013 and MAX16014)

Most battery-powered applications must include reverse voltage protection. Many times this is implemented with a diode in series with the battery. The disadvantage in using a diode is the forward voltage drop of the diode, which reduces the operating voltage available to downstream circuits ($V_{LOAD} = V_{BATTERY} - V_{DIODE}$). The MAX16013 and MAX16014 include high-voltage GATE1 drive circuitry allowing users to replace the high-voltage-drop series diode with a low-voltage-drop MOSFET device (as shown in the *Typical Operating Circuit* and Figure 3). The forward voltage drop is reduced to $I_{LOAD} \times R_{DS-ON}$ of P1. With a suitably chosen MOSFET, the voltage drop can be reduced to millivolts.

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In normal operating mode, internal GATE1 output circuitry enhances P1 to a 10V gate-to-source (V_{GS}) for $11V < V_{CC} < 72V$. The constant 10V enhancement ensures P1 operates in a low R_{DS-ON} mode, but the gate-source junction is not overstressed during high-battery-voltage application or transients (many MOSFET devices specify a $\pm 20V$ V_{GS} absolute maximum). As V_{CC} drops below 10V GATE1 is limited to GND, reducing P1 V_{GS} to $V_{CC} - GND$. In normal operation the P1 power dissipation is very low:

$$P1 = I_{LOAD}^2 \times R_{DS-ON}$$

During reverse-battery applications, GATE1 is limited to GND and the P1 gate-source junction is reverse biased. P1 is turned off and neither the MAX16013/MAX16014 nor the load circuitry is exposed to the reverse-battery voltage. Care should be taken to place P1 (and its internal drain-to-source diode) in the correct orientation for proper reverse battery operation.

P2 protects the load from input overvoltage conditions. During normal operating modes (the monitored voltage is below the adjusted overvoltage threshold), internal GATE2 output circuitry enhances P2 to a 10V gate-to-source (V_{GS}) for $11V < V_{CC} < 72V$. The constant 10V enhancement ensures P2 operates in a low R_{DS-ON} mode but the gate-to-source junction is not overstressed during high-battery-voltage applications (many pFET devices specify a $\pm 20V$ V_{GS} absolute maximum). As V_{CC} drops below 10V, GATE2 is limited to GND, reducing P2 V_{GS} to $V_{CC} - GND$. In normal operation, the P2 power dissipation is very low:

$$P2 = I_{LOAD}^2 \times R_{DS-ON}$$

During overvoltage conditions, P2 is either turned completely off (overvoltage-switch mode) or cycled off-on-off (voltage-limiter mode). Care should be taken to place P2 (and its internal drain-to-source diode) in the correct orientation for proper overvoltage protection operation. During voltage-limiter mode, the drain of P2 is limited to the adjusted overvoltage threshold, while the battery (V_{CC}) voltage rises. During prolonged overvoltage events, P2 temperature can increase rapidly due to the high power dissipation. The power dissipated by P2 is:

$$\begin{aligned} P2 &= V_{DS-P2} \times I_{LOAD} \\ &= (V_{CC} - V_{OV-ADJUSTED}) \times I_{LOAD} \end{aligned}$$

where $V_{CC} \sim V_{BATTERY}$ and $V_{OV-ADJUSTED}$ is the desired load limit voltage. For prolonged overvoltage events with high P2 power dissipation, proper heatsinking is required.

Adding External Pullup Resistors

It may be necessary to add an external resistor from V_{CC} to GATE1 to provide enough additional pullup capability when the GATE1 input goes high. The GATE_ output can only source up to $1\mu A$ current. If the source current is less than $1\mu A$, no external resistor may be necessary. However, to improve the pullup capability of the GATE_ output when it goes high, connect an external resistor between V_{CC} and the GATE_. The application shows a $2M\Omega$ resistor, which is large enough not to impact the sinking capability of the GATE_ (during normal operation) while providing enough pullup during an overvoltage event. With an 11V (worst case) V_{CC} -to-gate clamp voltage and a sinking current of $75\mu A$, the smallest resistor should be $11V/75\mu A$, or about $147k\Omega$. However, since the GATE_ is typically low most of the time, a higher value should be used to reduce overall power consumption.

Ultra-Small, Overvoltage Protection/ Detection Circuits

Functional Diagrams

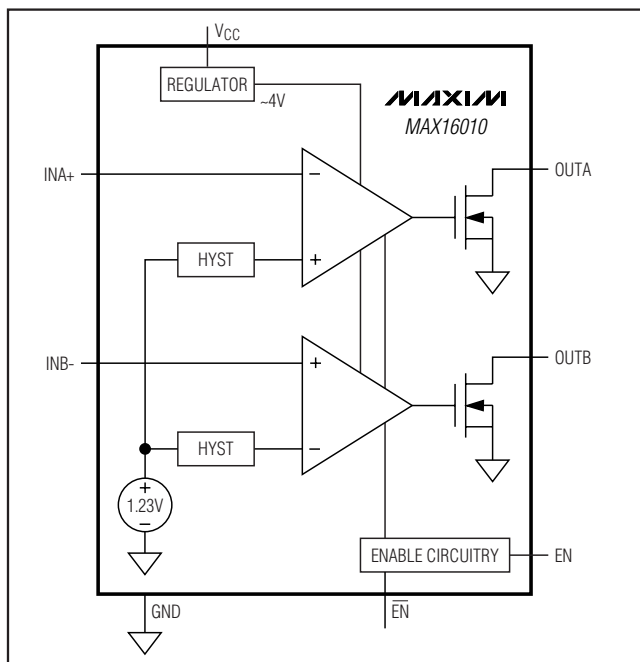


Figure 5. MAX16010 Functional Diagram

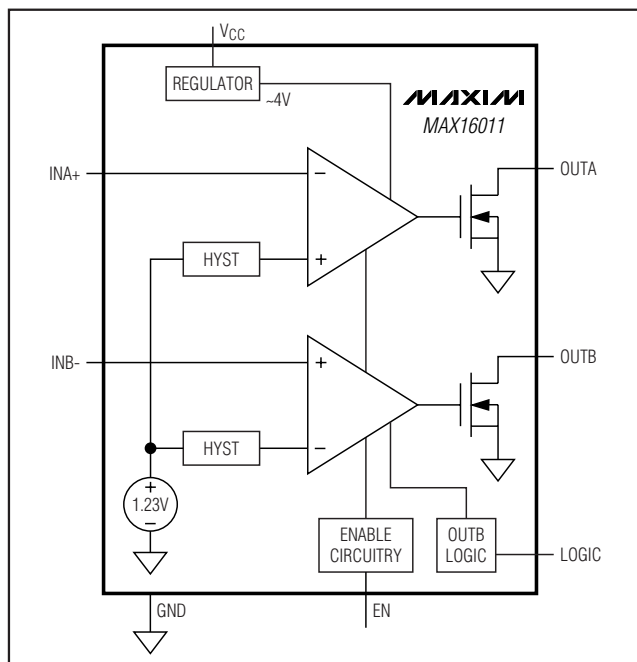


Figure 6. MAX16011 Functional Diagram

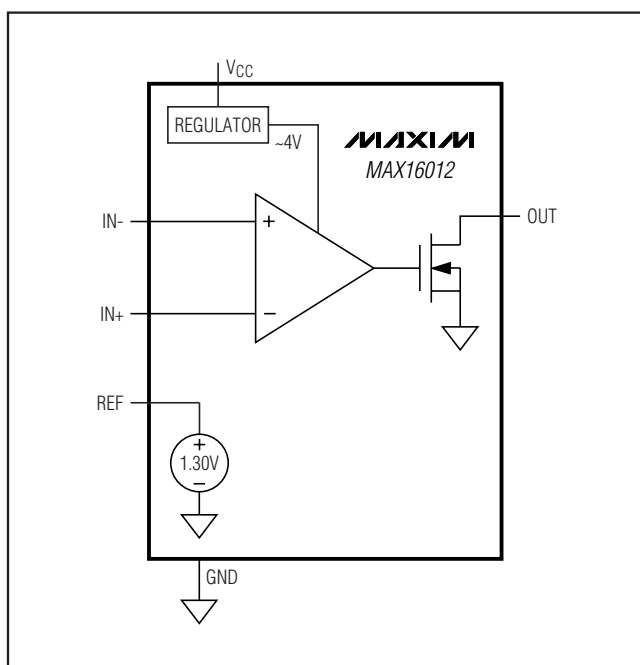


Figure 7. MAX16012 Functional Diagram

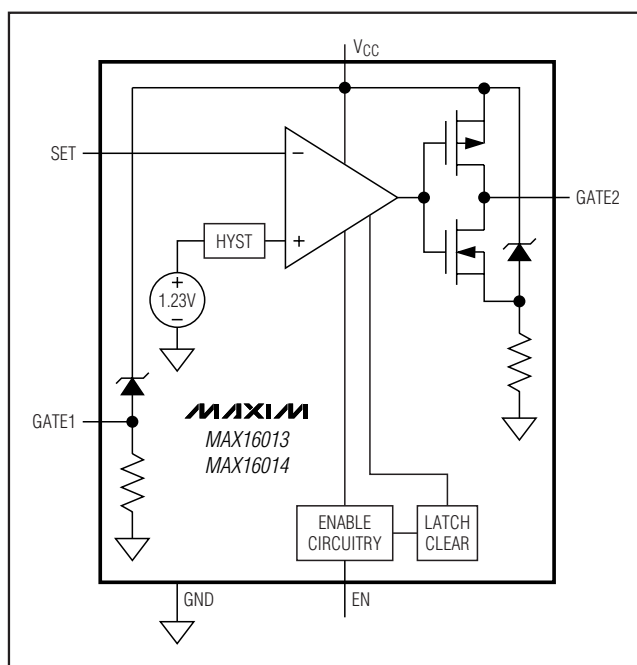


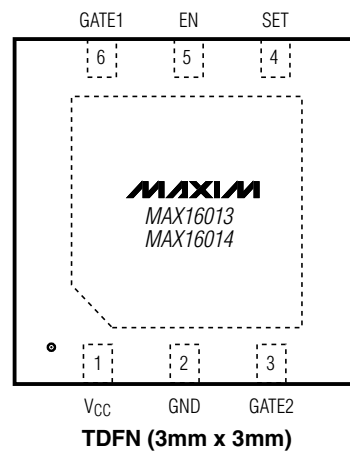
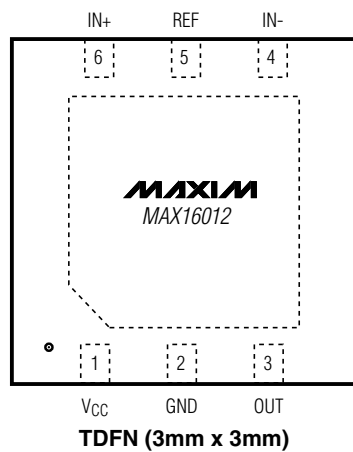
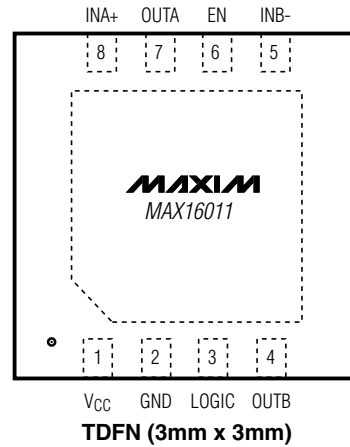
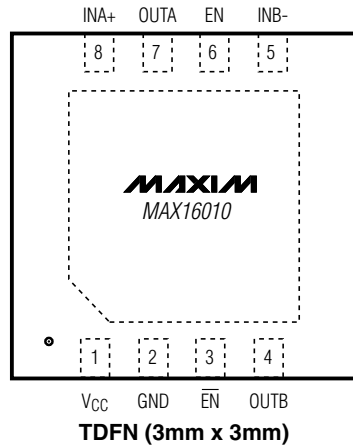
Figure 8. MAX16013/MAX16014 Functional Diagram

Ultra-Small, Overvoltage Protection/ Detection Circuits

Pin Configurations

MAX16010-MAX16014

TOP VIEW



Chip Information

PROCESS: BiCMOS

Package Information

For the latest package outline information and land patterns, go to www.maxim-ic.com/packages.

PACKAGE TYPE	PACKAGE CODE	DOCUMENT NO.
6 TDFN	T633-2	21-0137
8 TDFN	T833-2	21-0137

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Revision History

REVISION NUMBER	REVISION DATE	DESCRIPTION	PAGES CHANGED
0	6/05	Initial release	—
1	12/05	Removed future product designation for MAX16010/MAX16011	1, 12
2	1/07	Edited Figure 7	1, 10, 12
3	12/07	Fixed text in <i>Voltage Monitoring</i> section and updated Package Outline	6, 12
4	9/08	Revised Figures 6 and 8.	10

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- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



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